

1.Description

The TPD4E001DRLR-SL is designed to protect voltage sensitive components from ESD and transient voltage events. Excellent clamping capability. Low leakage, and fast response time, make these parts ideal for ESD protection on designs where board space is at a premium.

2.Features

- IEC 61000-4-2 Level 4 ESD Protection
 - $\pm 12\text{kV}$ Contact Discharge
 - $\pm 17\text{kV}$ Air Discharge
- IEC 61000-4-4 EFT Protection
 - 40A (5/50ns)
- IEC 61000-4-5 Surge
 - 4.0A (8/20us)
- RoHS compliance
- Protecting four I/O line
- Ultra-low Capacitance:0.6pF (Typical)
- Low clamping voltage
- Low leakage current
- Solid-state silicon technology

3.Applications

- Cellular Handsets & Accessories
- Cordless Phones
- Personal Digital Assistants (PDA's)
- Portable Instrumentation
- Notebooks & Handhelds
- Digital Cameras

4.Ordering Information

Part Number	Package	Marking	Material	Packing	Quantity per reel	Flammability Rating	Reel Size
TPD4E001DRLR-SL	SOT-563	.E54	Halogen free	Tape & Reel	3.000 PCS	UL 94V-0	7 inches

Table-1 Ordering information

5.Pin Configuration and Functions

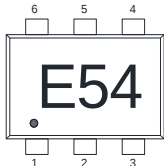
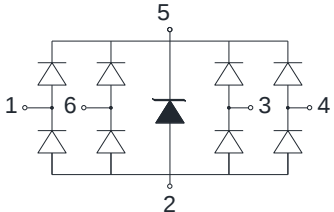
Pin	Name	Description	Outline	Circuit Diagram
1	IO	Connect to IO		
2	GND	Connect to GND		
3	IO	Connect to IO		
4	IO	Connect to IO		
5	VCC	Connect to Vcc		
6	IO	Connect to IO		

Table-2 Pin configuration

6.Specification

6.1. Absolute Maximum rating

Over operating free-air temperature range (unless otherwise noted)

Parameters	Symbol	Min.	Max.	Unit
Peak pulse power (tp=8/20us)@25°C	P _{pk}	-	60	W
Peak pulse current (tp=8/20us)@25°C	I _{PP}		4.0	A
ESD (IEC61000-4-2 air discharge) @25°C	V _{ESD}	-	±17	kV
ESD (IEC61000-4-2 contact discharge) @25°C	V _{ESD}	-	±12	kV
Junction temperature	T _J	-	150	°C
Operating temperature	T _{OP}	-40	125	°C
Storage temperature	T _{STG}	-55	150	°C
Lead temperature	T _L	-	260	°C

Table-3 Absolute Maximum rating

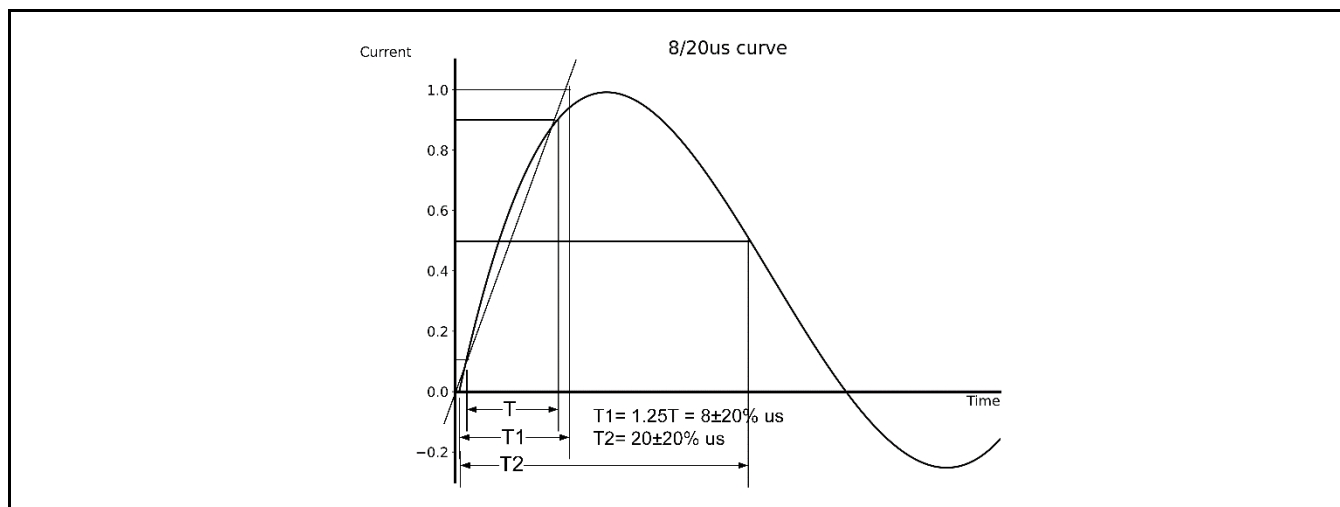
6.2. Electrical Characteristics

At TA = 25°C unless otherwise noted

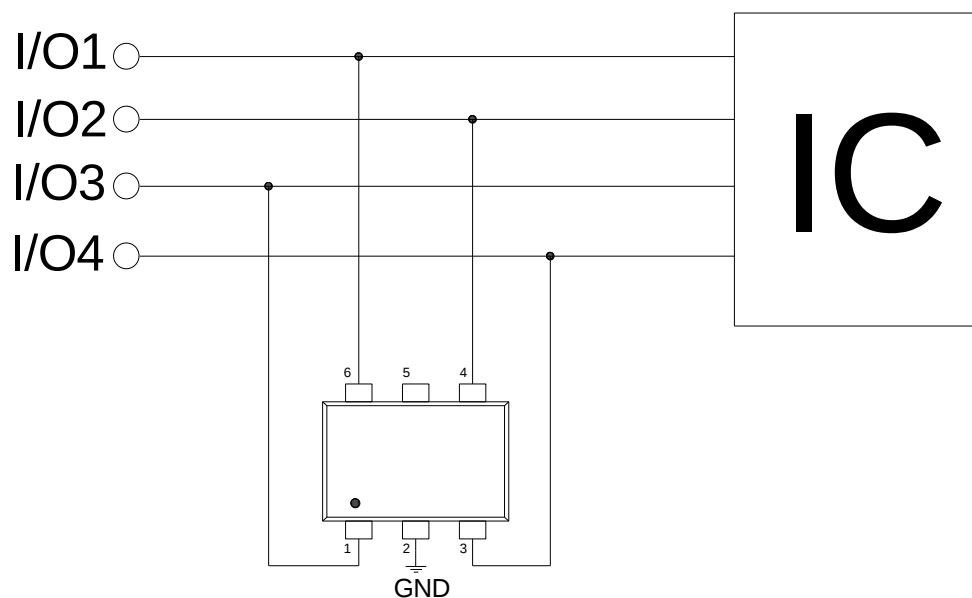
Parameters	Symbol	conditions	Min.	Typ.	Max.	Unit
Reverse stand-off voltage	V_{RWM}				5.0	V
Reverse Breakdown Voltage	V_{BR}	$I_T = 1mA$	6.0			V
Reverse Leakage Current	I_R	$V_{RWM}=5V$			1.0	uA
Peak Pulse Current	I_{PP}	TP=8/20us@25°C		4.0		A
Clamping Voltage	V_{CL}	$I_{PP}=1.0A$; TP=8/20us		8.5	10.0	V
Clamping Voltage	V_{CL}	$I_{PP}=4.0A$; TP=8/20us		12.0	15.0	V
Junction capacitance	CJ	I/O pins to ground; VR=0V; f = 1MHz		0.6	0.8	pF
		Between I/O pins; VR=0V; f = 1MHz		0.3	0.4	

Table-4 Electrical Characteristics

7. Typical Characteristic



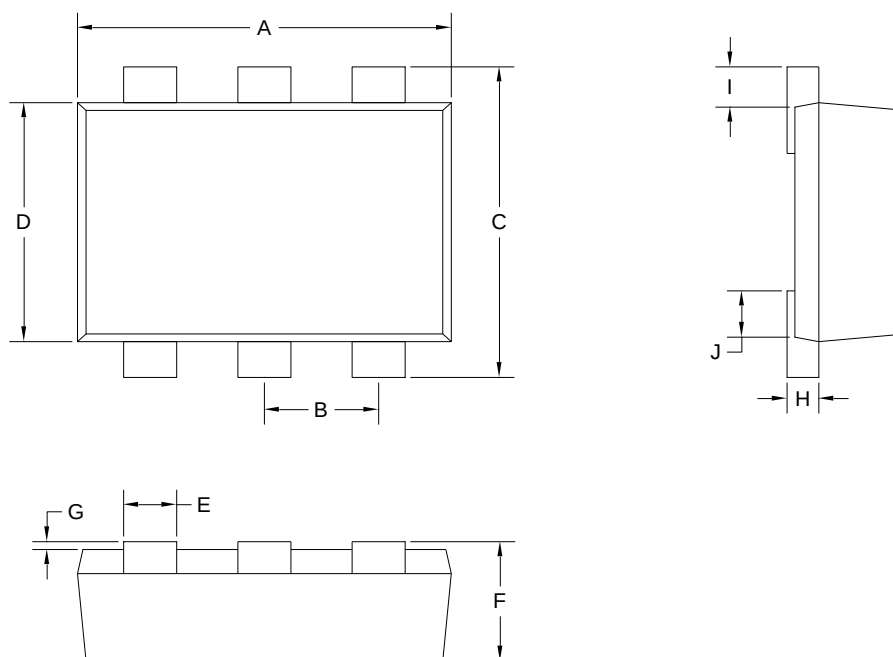
8. Typical Application



TPD4E001DRLR-SL

Typical Interface Application

9.Dimensions (SOT-563)



Units in millimeters

symbol	A	B	C	D	E	F	G	H	I	J
Min.	1.50	0.50	1.55	1.10	0.15	0.50	0.00	0.10	0.10	0.15
Max.	1.70	0.60	1.70	1.25	0.30	0.60	0.05	0.18	0.30	0.20